

30V N-Channel Trench MOSFET(Preliminary)

Features		Product S	Summary	
Trench Power Technology		VDS	30V	
 Low R_{DS(ON)} Low Gate Charge 		R _{DS(ON)} (at V _{GS} R _{DS(ON)} (at V _{GS}		
Optimized for Fast-switching Application	 Optimized for Fast-switching Applications 		/) 90A	
 Applications Synchronous Rectification in DC/DC a Isolated DC/DC Converters in Telecon 		100% UIS Tes	RoH	s
TO-252 $\bigcap_{G \ D \ S}$ D $\int_{G \ D \ S}$ f				
Device	Package		Marking	
TTD90N03AT	TO-252		90N03AT	

Absolute Maximum Ratin	gs $T_c = 25^{\circ}C$, unles	s otherwise noted		
Parameter		Symbol	Value	Unit
Drain-Source Voltage (V _{GS} = 0V)		V _{DSS}	30	V
Continuous Drain Current ^B	$T_{\rm C} = 25^{\circ}{\rm C}$		51	
	T _C = 100°C	I _D	51	A
Pulsed Drain Current ^A		I _{DM}	270	Α
Gate-Source Voltage		V _{GS}	±20	V
Single Pulse Avalanche Energy L =0.3mH ^A		E _{AS}	72	mJ
Avalanche Current ^A		I _{As}	22	А
Power Dissipation ^C	T _C = 25°C	P _D	108	W
	T _C = 100°C	P _D	82	W
Operating Junction and Storage Temperature Range		T _J , T _{SGT}	-55~+175	°C

Thermal Resistance				
Parameter	Symbol	Value	Unit	
Thermal Resistance, Junction-to-Case	R _{thJC}	1.45	00044	
Thermal Resistance, Junction-to-Ambient	R _{thJA}	100	°C/W	



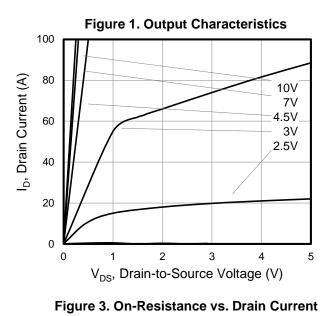
Specifications $T_J = 25^{\circ}C$, u				N/ 1		
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Тур.	Max.	
Static				1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 250\mu A$	30			V
Zana Cata Valtana Durin Cumunt		$V_{DS} = 30V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30V, V_{GS} = 0V, T_{J} = 100^{\circ}C$			25	
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 20V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0	1.7	2.4	V
Statia Drain Course On Desistence		$V_{GS} = 10V, I_{D} = 30A$		3.6	5.0	mΩ
Static Drain-Source On-Resistance	R _{DS(on)}	$V_{GS} = 4.5 V, I_{D} = 30 A$		5	7.0	mΩ
Forward Transconductance	g _{fs}	V _{DS} = 10V, I _D =20A	17.3			S
Dynamic						
Input Capacitance	C _{iss}			1608		
Output Capacitance	C _{oss}	V _{GS} = 0V, V _{DS} = 15V, f = 1.0MHz		513		pF
Reverse Transfer Capacitance	C _{rss}			297		
Total Gate Charge	Qg			62		
Gate-Source Charge	Q _{gs}	$V_{DD} = 15V, I_{D} = 50A, V_{GS} = 10V$		7		nC
Gate-Drain Charge	Q _{gd}	00 -		13		
Turn-on Delay Time	t _{d(on)}			13		
Turn-on Rise Time	t _r	V _{DD} = 15V, I _D = 50A,		17		
Turn-off Delay Time	t _{d(off)}	$R_{\rm G} = 3\Omega$		42		ns
Turn-off Fall Time	t _f			13		
Drain-Source Body Diode Character	istics				. 1	
Continuous Body Diode Current ^B	۱ _S	_			46	۸
Pulsed Diode Forward Current ^A	I _{SM}	$T_{\rm C} = 25^{\circ}{\rm C}$			270	A
Body Diode Voltage	V _{SD}	T _J = 25°C, I _{SD} = 30A, V _{GS} = 0V			1.2	V
Reverse Recovery Time	t _{rr}	I _F = 30A,		40		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt = 100A/µs		88		nC

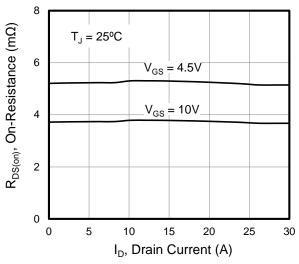
Notes

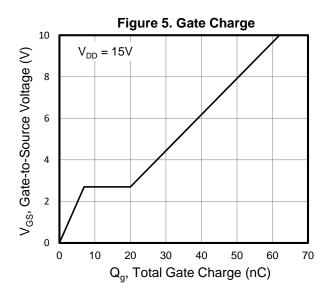
- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. $V_{DD} = 30V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1%

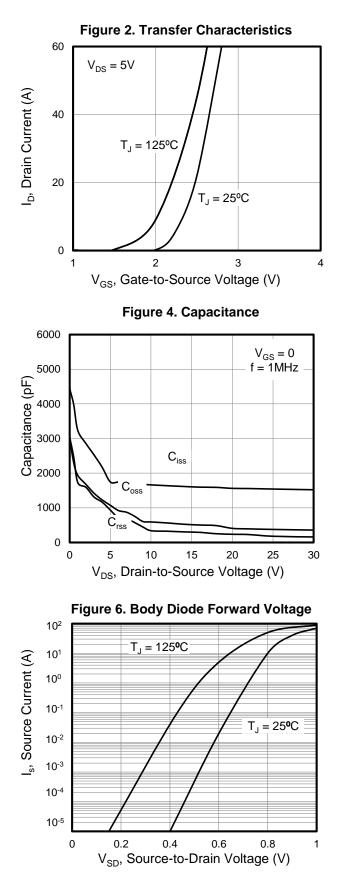


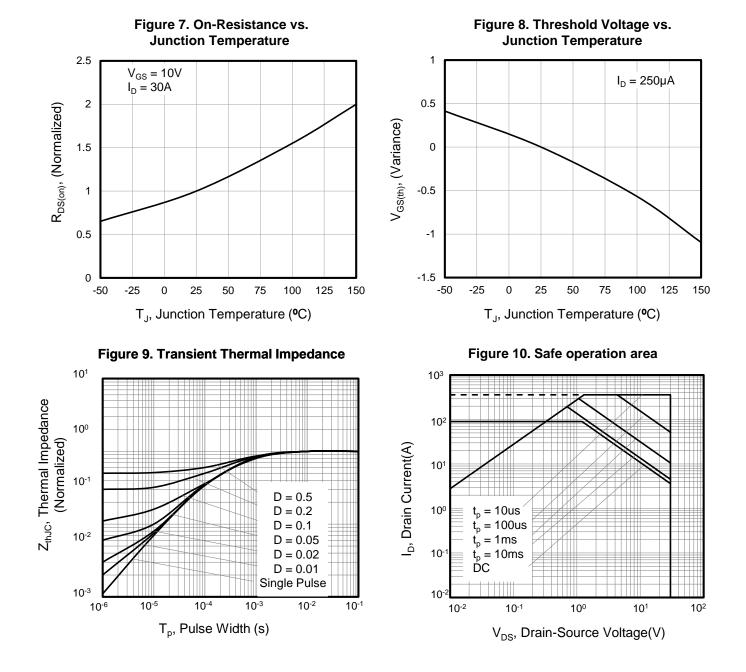
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted



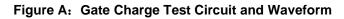


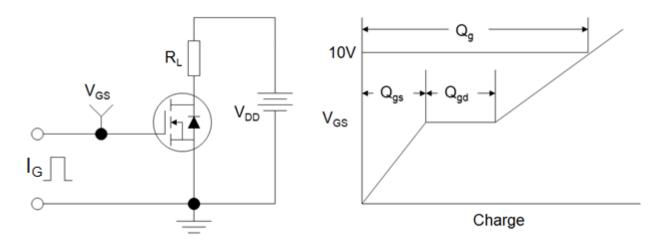


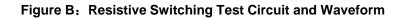




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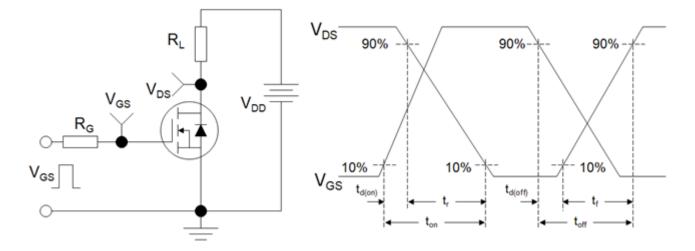
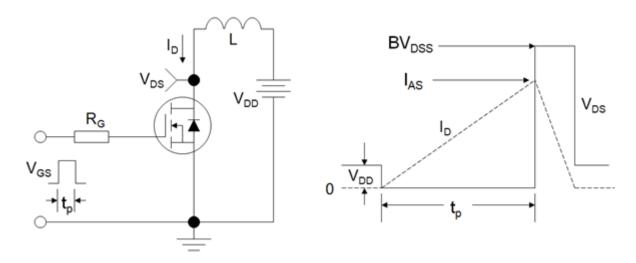
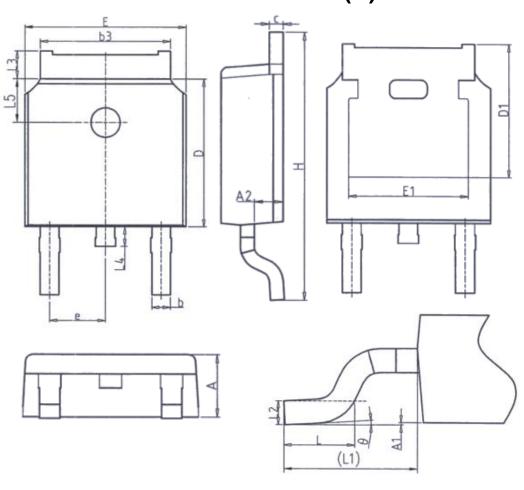


Figure C: Unclamped Inductive Switching Test Circuit and Waveform





TO-252(H)



Unit: mm				
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.20		
A2	0.97	1.17		
b	0.68	0.90		
b3	5.20	5.50		
с	0.43	0.63		
D	5.98	6. 22		
D1	5. 30REF			
E	6.40	6.80		
E1	4.63	-		

Unit: mm			
Symbol	Min.	Max.	
e	2. 286BSC		
Н	9.40	10.50	
L	1.38	1.75	
L1	2.90REF		
L2	0. 51BSC		
L3	0.88	1.28	
L4	-	1.00	
L5	1.65	1.95	
θ	0°	8°	



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